## $3.2 \Omega$, Fast Switching Speed, +12 V / +5 V / +3 V / $\pm 5$ V, 4- / 8-Channel Analog Multiplexers

## DESCRIPTION

The DG9408E, DG9409E uses BiCMOS wafer fabrication technology that allows the DG9408E, DG9409E to operate on single and dual supplies. Single supply voltage ranges from 3 V to 16 V while dual supply operation is recommended with $\pm 3 \mathrm{~V}$ to $\pm 8 \mathrm{~V}$.
The DG9408E is an 8-channel single-ended analog multiplexer designed to connect one of eight inputs to a common output as determined by a 3-bit binary address $\left(A_{0}, A_{1}, A_{2}\right)$. The DG9409E is a dual 4-channel differential analog multiplexer designed to connect one of four differential inputs to a common dual output as determined by its 2-bit binary address ( $A_{0}, A_{1}$ ). Break-before-make switching action to protect against momentary crosstalk between adjacent channels.
As a committed partner to the community and the environment, Vishay Siliconix manufactures this product with lead (Pb)-free device terminations. The DG9408E, DG9409E are offered in a QFN package that has a nickel-palladium-gold device terminations and is represented by the lead (Pb)-free "-E4" suffix. The nickel-palladium-gold device terminations meet all the JEDEC ${ }^{\circledR}$ standards for reflow and MSL ratings.

## FEATURES

- 3 V to 16 V single supply or $\pm 3 \mathrm{~V}$ to $\pm 8 \mathrm{~V}$ dual supply operation

- Low on-resistance - R $\mathrm{R}_{\mathrm{ON}} 3.2 \Omega$ typ.
- Fast switching: $\mathrm{t}_{\mathrm{ON}}-36 \mathrm{~ns}, \mathrm{t}_{\text {OFF }}-24 \mathrm{~ns}$
- Break-before-make guaranteed
- Low leakage
- TTL, CMOS, LV logic (3 V) compatible
- 2500 V ESD protection (HBM)
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912


## BENEFITS

- Fast switching speed
- Low switch resistance
- Wide operation voltage range
- Simple logic interface


## APPLICATIONS

- Automatic test equipment
- Process control and automation
- Data acquisition systems
- Meters and instruments
- Medical and healthcare systems
- Communication systems
- Audio and video signal routing
- Relay replacement
- Battery powered systems


## FUNCTIONAL BLOCK DIAGRAM AND PIN CONFIGURATION



Note

- QFN16 package central exposed pad has no electrical connection inside the chip. It can be connected GND, V+, V-, or left floating.

DG9408E, DG9409E

## TRUTH TABLE AND ORDERING INFORMATION

| TRUTH TABLE DG9408E |  |  |  |  |
| :---: | :---: | :---: | :---: | :---: |
| $\mathbf{A}_{\mathbf{2}}$ | $\mathbf{A}_{\mathbf{1}}$ | $\mathbf{A}_{\mathbf{0}}$ | $\overline{\text { EN }}$ | ON SWITCH |
| X | X | X | 1 | None |
| 0 | 0 | 0 | 0 | 1 |
| 0 | 0 | 1 | 0 | 2 |
| 0 | 1 | 0 | 0 | 3 |
| 0 | 1 | 1 | 0 | 4 |
| 1 | 0 | 0 | 0 | 5 |
| 1 | 0 | 1 | 0 | 6 |
| 1 | 1 | 0 | 0 | 7 |
| 1 | 1 | 1 | 0 | 8 |

TRUTH TABLE DG9409E

| $\mathbf{A}_{\mathbf{1}}$ | $\mathbf{A}_{\mathbf{0}}$ | $\mathbf{E N}$ | ON SWITCH |
| :---: | :---: | :---: | :---: |
| X | X | 1 | None |
| 0 | 0 | 0 | 1 |
| 0 | 1 | 0 | 2 |
| 1 | 0 | 0 | 3 |
| 1 | 1 | 0 | 4 |

$X=$ do not care

For low and high voltage levels for $\mathrm{V}_{\mathrm{AX}}$ and $\mathrm{V}_{\mathrm{EN}}$ consult "Digital Control" parameters for specific $\mathrm{V}+$ operation. See specifications tables for:

Single supply 12 V
Dual supply $\mathrm{V}+=5 \mathrm{~V}, \mathrm{~V}-=-5 \mathrm{~V}$
Single supply 5 V
Single supply 3 V

## ORDERING INFORMATION

| TEMP. RANGE | PACKAGE | PART NUMBER | MIN. ORDER / PACK. QUANTITY |
| :---: | :---: | :---: | :---: |
| $-40^{\circ} \mathrm{C}$ to $+85^{\circ} \mathrm{C}$ | 16-pin QFN $(4 \mathrm{~mm} \times 4 \mathrm{~mm})$ <br> (variation 1$)$ | DG9408EDN-T1-GE4 | Tape and reel, 2500 units |
|  | DG9409EDN-T1-GE4 | Tape and reel, 2500 units |  |


| ABSOLUTE MAXIMUM RATINGS ( $\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$, unless otherwise noted) |  |  |  |
| :---: | :---: | :---: | :---: |
| PARAMETER |  | LIMIT | UNIT |
| Voltage referenced V+ to V- |  | -0.3 to +18 | V |
| GND to V- |  | 18 |  |
| Digital inputs ${ }^{\mathrm{a}}, \mathrm{V}_{\mathrm{S}}, \mathrm{V}_{\mathrm{D}}$ |  | (V-) - 0.3 to (V+)+0.3 |  |
| Current (any terminal except S or D) |  | 30 | mA |
| Continuous current, S or D |  | 100 |  |
| Peak current, S or D (pulsed at $1 \mathrm{~ms}, 10$ \% duty cycle max.) |  | 200 |  |
| Package solder reflow conditions (lead (Pb)-free assembly) ${ }^{\text {d }}$ | 16-pin (4 x 4 mm) QFN | $260+0 /-5$ | ${ }^{\circ} \mathrm{C}$ |
| Storage temperature |  | -65 to +150 |  |
| Power dissipation (package) ${ }^{\mathrm{b}}$, $\left(\mathrm{T}_{\mathrm{A}}=70^{\circ} \mathrm{C}\right)$ | 16-pin ( $4 \times 4 \mathrm{~mm}$ ) QFN ${ }^{\text {c }}$ | 1880 | mW |
| ESD human body model (HBM), per ANSI / ESDA / JEDEC ${ }^{\circledR}$ JS-001 |  | 2500 | V |
| Latch up current, per JESD78 |  | 400 | mA |

## Notes

a. Signals on SX, DX or INX exceeding V+ or V- will be clamped by internal diodes. Limit forward diode current to maximum current ratings.
b. All leads soldered or welded to PC board.
c. Derate $23.5 \mathrm{~mW} /{ }^{\circ} \mathrm{C}$ above $70^{\circ} \mathrm{C}$.
d. Manual soldering with soldering iron is not recommended for leadless components. The QFN is a leadless package. The end of the lead terminal is exposed copper (not plated) as a result of the singulation process in manufacturing. A solder fillet at the exposed copper lip cannot be guaranteed and is not required to ensure adequate bottom side solder interconnection

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

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| SPECIFICATIONS (Single Supply 12 V ) |  |  |  |  |  |  |  |  |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| PARAMETER | SYMBOL | TEST CONDITIONS UNLESS OTHERWISE SPECIFIED$\begin{gathered} \mathrm{V}_{+}=12 \mathrm{~V}, \pm 10 \%, \mathrm{~V}-=0 \mathrm{~V} \\ \mathrm{~V}_{\mathrm{A}}, \mathrm{~V}_{\mathrm{EN}}=0.8 \mathrm{~V} \text { or } 2.4 \mathrm{~V}^{\mathrm{f}} \end{gathered}$ |  | TEMP. ${ }^{\text {b }}$ | $\begin{gathered} \text { LIMITS } \\ -40^{\circ} \mathrm{C} \text { to }+85^{\circ} \mathrm{C} \end{gathered}$ |  |  | UNIT |
|  |  |  |  | MIN. ${ }^{\text {c }}$ | TYP. ${ }^{\text {d }}$ | MAX. ${ }^{\text {c }}$ |  |
| Analog Switch |  |  |  |  |  |  |  |  |
| Analog signal range ${ }^{\text {e }}$ | $\mathrm{V}_{\text {ANALOG }}$ |  |  |  | Full | 0 | - | 12 | V |
| On-resistance | Ron | $\mathrm{V}+=10.8 \mathrm{~V}, \mathrm{~V}_{\mathrm{D}}=2 \mathrm{~V} \text { or } 9 \mathrm{~V}, \mathrm{I}_{\mathrm{S}}=50 \mathrm{~mA}$ <br> sequence each switch on |  | Room | - | 3.2 | 7 | $\Omega$ |
|  |  |  |  | Full | - |  | 7.5 |  |
| Ron match between channels 9 | $\Delta \mathrm{R}_{\text {ON }}$ | $\mathrm{V}+=10.8 \mathrm{~V}, \mathrm{~V}_{\mathrm{D}}=2 \mathrm{~V}$ or $9 \mathrm{~V}, \mathrm{I}_{\mathrm{S}}=50 \mathrm{~mA}$ |  | Room | - | - | 3.6 |  |
| On-resistance flatness ${ }^{\text {i }}$ | $\mathrm{R}_{\mathrm{ON}}$ flatness |  |  | Room | - | - | 8 |  |
| Switch off leakage current | $\mathrm{I}_{\text {S(off) }}$ | $\mathrm{V}_{\text {EN }}=2.4 \mathrm{~V}, \mathrm{~V}_{\mathrm{D}}=11 \mathrm{~V}$ or $1 \mathrm{~V}, \mathrm{~V}_{\mathrm{S}}=1 \mathrm{~V}$ or 11 V |  | Room | -2 | - | 2 | nA |
|  |  |  |  | Full | -15 | - | 15 |  |
|  | $I_{\text {(offi) }}$ |  |  | Room | -2 | - | 2 |  |
|  |  |  |  | Full | -15 | - | 15 |  |
| Channel on leakage current | $I_{\text {d(on) }}$ | $\mathrm{V}_{\mathrm{EN}}=0 \mathrm{~V}, \mathrm{~V}_{\mathrm{S}}=\mathrm{V}_{\mathrm{D}}=1 \mathrm{~V}$ or 11 V |  | Room | -2 | - | 2 |  |
|  |  |  |  | Full | -15 | - | 15 |  |
| Digital Control |  |  |  |  |  |  |  |  |
| Logic high input voltage | $\mathrm{V}_{\text {INH }}$ |  |  | Full | 2.4 | - | - | V |
| Logic low input voltage | $\mathrm{V}_{\text {INL }}$ |  |  | Full | - | - | 0.8 |  |
| Input current | IN | $\mathrm{V}_{\mathrm{AX}}=\mathrm{V}_{\text {EN }}=2.4 \mathrm{~V}$ or 0.8 |  | Full | -1 | - | 1 | $\mu \mathrm{A}$ |
| Dynamic Characteristics |  |  |  |  |  |  |  |  |
| Transition time | $t_{\text {trans }}$ | $\begin{gathered} \mathrm{V}_{\mathrm{S} 1}=8 \mathrm{~V}, \mathrm{~V}_{\mathrm{S} 8}=0 \mathrm{~V},(\text { (DG9408E) } \\ \mathrm{V}_{\mathrm{S} 1 \mathrm{~b}}=8 \mathrm{~V}, \mathrm{~V}_{\mathrm{S} 4 \mathrm{~b}}=0 \mathrm{~V},(\mathrm{DG9409E}) \\ \text { see fig. } 2 \end{gathered}$ |  | Room | - | 40 | 71 | ns |
|  |  |  |  | Full | - | - | 75 |  |
| Break-before-make time | $\mathrm{t}_{\text {BBM }}$ | $V_{S(\text { all }}=V_{D A}=5 \mathrm{~V}$ <br> see fig. 4 |  | Room | 2 | 20 | - |  |
|  |  |  |  | Full | - | - | - |  |
| Enable turn-on time | $\mathrm{t}_{\mathrm{ON}(\mathrm{EN})}$ | $\begin{gathered} \mathrm{V}_{\mathrm{AX}}=0 \mathrm{~V}, \mathrm{~V}_{\mathrm{S} 1}=5 \mathrm{~V}(\mathrm{DG9408E}) \\ \mathrm{V}_{\mathrm{AX}}=0 \mathrm{~V}, \mathrm{~V}_{\mathrm{S} 1 \mathrm{~b}}=5 \mathrm{~V} \text { (DG9409E) } \\ \text { see fig. } 3 \end{gathered}$ |  | Room | - | 36 | 70 |  |
|  |  |  |  | Full | - | - | 75 |  |
| Enable turn-off time | toff(EN) |  |  | Room | - | 24 | 44 |  |
|  |  |  |  | Full | - | - | 46 |  |
| Charge injection ${ }^{\text {e }}$ | Q | $\mathrm{C}_{\mathrm{L}}=1 \mathrm{nF}, \mathrm{V}_{\mathrm{GEN}}=0 \mathrm{~V}, \mathrm{R}_{\mathrm{GEN}}=0 \Omega$ |  | Room | - | 4.5 | - | pC |
| Off isolation ${ }^{\text {e, }} \mathrm{h}$ | OIRR | $\mathrm{f}=100 \mathrm{kHz}, \mathrm{R}_{\mathrm{L}}=1 \mathrm{k} \Omega$ |  | Room | - | -83 | - | dB |
| Crosstalk ${ }^{\text {e }}$ | $\mathrm{X}_{\text {TALK }}$ |  |  | Room | - | -89 | - |  |
| Source off capacitance ${ }^{e}$ | $\mathrm{C}_{\text {(off) }}$ | $\mathrm{f}=1 \mathrm{MHz}, \mathrm{V}_{\mathrm{S}}=0 \mathrm{~V}, \mathrm{~V}_{\text {EN }}=2.4 \mathrm{~V}$ | DG9408E | Room | - | 17 | - | pF |
|  |  |  | DG9409E | Room | - | 16 | - |  |
| Drain off capacitance ${ }^{\text {e }}$ | $\mathrm{C}_{\mathrm{D} \text { (off) }}$ | $\mathrm{f}=1 \mathrm{MHz}, \mathrm{V}_{\mathrm{D}}=0 \mathrm{~V}, \mathrm{~V}_{\text {EN }}=2.4 \mathrm{~V}$ | DG9408E | Room | - | 134 | - |  |
|  |  |  | DG9409E | Room | - | 67 | - |  |
| Drain on capacitance ${ }^{\text {e }}$ | $C_{\text {D(on) }}$ | $\mathrm{f}=1 \mathrm{MHz}, \mathrm{V}_{\mathrm{D}}=0 \mathrm{~V}, \mathrm{~V}_{\mathrm{EN}}=0 \mathrm{~V}$ | DG9408E | Room | - | 154 | - |  |
|  |  |  | DG9409E | Room | - | 86 | - |  |
| Power Supplies |  |  |  |  |  |  |  |  |
| Power supply current | I+ | $\mathrm{V}_{\text {EN }}=\mathrm{V}_{\mathrm{A}}=0 \mathrm{~V}$ or $\mathrm{V}+$ |  | Room | - | - | 1 | $\mu \mathrm{A}$ |

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| SPECIFICATIONS (Dual Supply $\mathrm{V}+=5 \mathrm{~V}, \mathrm{~V}-=-5 \mathrm{~V}$ ) |  |  |  |  |  |  |  |  |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| PARAMETER | SYMBOL | TEST CONDITIONS UNLESS OTHERWISE SPECIFIED$\begin{gathered} \mathrm{V}+=5 \mathrm{~V}, \mathrm{~V}-=-5 \mathrm{~V}, \pm 10 \% \\ \mathrm{~V}_{\mathrm{A}}, \mathrm{~V}_{\overline{\mathrm{EN}}}=0.8 \mathrm{~V} \text { or } 2 \mathrm{~V}^{\mathrm{f}} \end{gathered}$ |  | TEMP. ${ }^{\text {b }}$ | $\begin{gathered} \text { LIMITS } \\ -40^{\circ} \mathrm{C} \text { to }+85^{\circ} \mathrm{C} \\ \hline \end{gathered}$ |  |  | UNIT |
|  |  |  |  | MIN. ${ }^{\text {c }}$ | TYP. ${ }^{\text {d }}$ | MAX. ${ }^{\text {c }}$ |  |
| Analog Switch |  |  |  |  |  |  |  |  |
| Analog signal range ${ }^{\text {e }}$ | $\mathrm{V}_{\text {ANALOG }}$ |  |  |  | Full | -5 | - | 5 | V |
| On-Resistance | Ron | $\mathrm{V}+=4.5 \mathrm{~V}, \mathrm{~V}-=-4.5 \mathrm{~V}, \mathrm{~V}_{\mathrm{D}}= \pm 3.5 \mathrm{~V}, \mathrm{I}_{\mathrm{S}}=50 \mathrm{~mA}$ <br> sequence each switch on |  | Room | - | 4 | 8 | $\Omega$ |
|  |  |  |  | Full | - | - | 8.5 |  |
| RON match between channels 9 | $\Delta \mathrm{R}_{\text {ON }}$ | $\mathrm{V}+=4.5 \mathrm{~V}, \mathrm{~V}-=-4.5 \mathrm{~V}, \mathrm{~V}_{\mathrm{D}}= \pm 3.5 \mathrm{~V}, \mathrm{I}_{\mathrm{S}}=50 \mathrm{~mA}$ |  | Room | - | - | 3.6 |  |
| On-resistance flatness ${ }^{\text {i }}$ | RoN Flatness |  |  | Room | - | - | 8.2 |  |
| Switch off leakage current ${ }^{\text {a }}$ | $\mathrm{I}_{\text {S(off) }}$ | $\begin{gathered} \mathrm{V}_{+}=5.5, \mathrm{~V}-=-5.5 \mathrm{~V} \\ \mathrm{~V}_{\mathrm{EN}}=2.4 \mathrm{~V}, \mathrm{~V}_{\mathrm{D}}= \pm 4.5 \mathrm{~V}, \mathrm{~V}_{\mathrm{S}}= \pm 4.5 \mathrm{~V} \end{gathered}$ |  | Room | -2 | - | 2 | nA |
|  |  |  |  | Full | -15 | - | 15 |  |
|  | $I_{\text {D(off) }}$ |  |  | Room | -2 | - | 2 |  |
|  |  |  |  | Full | -15 | - | 15 |  |
| Channel on leakage current ${ }^{\text {a }}$ | $I_{\text {don }}$ | $\begin{gathered} \mathrm{V}_{+}=5.5 \mathrm{~V}, \mathrm{~V}-=-5.5 \mathrm{~V} \\ \mathrm{~V}_{\mathrm{EN}}=0 \mathrm{~V}, \mathrm{~V}_{\mathrm{D}}= \pm 4.5 \mathrm{~V}, \mathrm{~V}_{\mathrm{S}}= \pm 4.5 \mathrm{~V} \end{gathered}$ |  | Room | -2 | - | 2 |  |
|  |  |  |  | Full | -15 | - | 15 |  |
| Digital Control |  |  |  |  |  |  |  |  |
| Logic high input voltage | $\mathrm{V}_{\text {INH }}$ |  |  | Full | 2 | - | - | V |
| Logic low input voltage | $\mathrm{V}_{\text {INL }}$ |  |  | Full | - | - | 0.8 |  |
| Input current ${ }^{\text {a }}$ | IN | $\mathrm{V}_{\mathrm{AX}}=\mathrm{V}_{\mathrm{EN}}=2 \mathrm{~V}$ or 0.8 |  | Full | -1 | - | 1 | $\mu \mathrm{A}$ |
| Dynamic Characteristics |  |  |  |  |  |  |  |  |
| Transition time ${ }^{\text {e }}$ | $t_{\text {trans }}$ | $\begin{gathered} \mathrm{V}_{\mathrm{S} 1}=3.5 \mathrm{~V}, \mathrm{~V}_{\mathrm{S} 8}=-3.5 \mathrm{~V},(\mathrm{DG9408E}) \\ \mathrm{V}_{\mathrm{S} 1 \mathrm{~b}}=3.5 \mathrm{~V}, \mathrm{~V}_{\mathrm{S} 4 \mathrm{~b}}=-3.5 \mathrm{~V},(\mathrm{DG9409E}) \\ \text { see fig. } 2 \end{gathered}$ |  | Room | - | 47 | 65 | ns |
|  |  |  |  | Full | - | - | 70 |  |
| Break-before-make time ${ }^{\text {e }}$ | $t_{\text {BBM }}$ | $\begin{aligned} & \mathrm{V}_{\mathrm{S}(\mathrm{all})}=\mathrm{V}_{\mathrm{DA}}=3.5 \mathrm{~V} \\ & \text { see fig. } 4 \end{aligned}$ |  | Room | 1 | 13 | - |  |
|  |  |  |  | Full | - | - | - |  |
| Enable turn-on time ${ }^{\text {e }}$ | ton(EN) | $\begin{gathered} \mathrm{V}_{\mathrm{AX}}=0 \mathrm{~V}, \mathrm{~V}_{\mathrm{S} 1}=3.5 \mathrm{~V}(\mathrm{DG9408E}) \\ \mathrm{V}_{\mathrm{AX}}=0 \mathrm{~V}, \mathrm{~V}_{\mathrm{S} 1 \mathrm{~b}}=3.5 \mathrm{~V}(\mathrm{DG9409E}) \\ \text { see fig. } 3 \end{gathered}$ |  | Room | - | 54 | 70 |  |
|  |  |  |  | Full | - | - | 76 |  |
| Enable turn-off time ${ }^{\text {e }}$ | $\mathrm{t}_{\text {OFF (EN) }}$ |  |  | Room | - | 28 | 40 |  |
|  |  |  |  | Full | - | - | 43 |  |
| Source off capacitance ${ }^{\text {e }}$ | $\mathrm{C}_{\text {S(fff) }}$ | $\mathrm{f}=1 \mathrm{MHz}, \mathrm{V}_{\mathrm{S}}=0 \mathrm{~V}, \mathrm{~V}_{\mathrm{EN}}=2 \mathrm{~V}$ | DG9408E | Room | - | 15 | - | pF |
|  |  |  | DG9409E | Room | - | 14 | - |  |
| Drain off capacitance ${ }^{\text {e }}$ | $\mathrm{C}_{\mathrm{D} \text { (off) }}$ | $\mathrm{f}=1 \mathrm{MHz}, \mathrm{V}_{\mathrm{D}}=0 \mathrm{~V}, \mathrm{~V}_{\mathrm{EN}}=2 \mathrm{~V}$ | DG9408E | Room | - | 126 | - |  |
|  |  |  | DG9409E | Room | - | 63 | - |  |
| Drain on capacitance ${ }^{\text {e }}$ | $C_{\text {D(on) }}$ | $\mathrm{f}=1 \mathrm{MHz}, \mathrm{V}_{\mathrm{D}}=0 \mathrm{~V}, \mathrm{~V}_{\mathrm{EN}}=0 \mathrm{~V}$ | DG9408E | Room | - | 153 | - |  |
|  |  |  | DG9409E | Room | - | 89 | - |  |
| Power Supplies |  |  |  |  |  |  |  |  |
| Power supply current | I+ | $\mathrm{V}_{\mathrm{EN}}=\mathrm{VA}=0 \mathrm{~V}$ or $\mathrm{V}_{+}$ |  | Room | - | - | 1 | $\mu \mathrm{A}$ |
|  | I- |  |  | Room | -1 | - | - |  |

DG9408E, DG9409E

| SPECIFICATIONS (Single Supply 5 V ) |  |  |  |  |  |  |  |  |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| PARAMETER | SYMBOL | TEST CONDITIONS UNLESS OTHERWISE SPECIFIED$\begin{gathered} \mathrm{V}+=5 \mathrm{~V}, \pm 10 \%, \mathrm{~V}=0 \mathrm{~V} \\ \mathrm{~V}_{\mathrm{A}}, \mathrm{~V}_{\mathrm{EN}}=0.8 \mathrm{~V} \text { or } 2 \mathrm{~V}^{\mathrm{f}} \end{gathered}$ |  | TEMP. ${ }^{\text {b }}$ | $\begin{gathered} \text { LIMITS } \\ -40^{\circ} \mathrm{C} \text { to }+85^{\circ} \mathrm{C} \end{gathered}$ |  |  | UNIT |
|  |  |  |  | MIN. ${ }^{\text {c }}$ | TYP. ${ }^{\text {d }}$ | MAX. ${ }^{\text {c }}$ |  |
| Analog Switch |  |  |  |  |  |  |  |  |
| Analog signal range ${ }^{\text {e }}$ | $\mathrm{V}_{\text {ANALOG }}$ |  |  |  | Full | 0 | - | 5 | V |
| On-resistance | $\mathrm{R}_{\mathrm{ON}}$ | $\mathrm{V}+=4.5 \mathrm{~V}, \mathrm{~V}_{\mathrm{D}}$ or $\mathrm{V}_{\mathrm{S}}=1 \mathrm{~V}$ or $3.5 \mathrm{~V}, \mathrm{I}_{\mathrm{S}}=50 \mathrm{~mA}$ |  | Room | - | 6.8 | 10.5 | $\Omega$ |
|  |  |  |  | Full | - | - | 11 |  |
| Row match between channels 9 | $\Delta \mathrm{R}_{\text {ON }}$ | $\mathrm{V}+=4.5 \mathrm{~V}, \mathrm{~V}_{\mathrm{D}}=1 \mathrm{~V}$ or $3.5 \mathrm{~V}, \mathrm{I}_{\mathrm{S}}=50 \mathrm{~mA}$ |  | Room | - | - | 3.6 |  |
| On-resistance flatness ${ }^{\text {i }}$ | $\mathrm{R}_{\mathrm{ON}}$ Flatness |  |  | Room | - | - | 9 |  |
| Switch off leakage current ${ }^{\text {a }}$ | $\mathrm{I}_{\text {S(off) }}$ | $\begin{gathered} \mathrm{V}+=5.5 \mathrm{~V} \\ \mathrm{~V}_{\mathrm{S}}=1 \mathrm{~V} \text { or } 4 \mathrm{~V}, \mathrm{~V}_{\mathrm{D}}=4 \mathrm{~V} \text { or } 1 \mathrm{~V} \end{gathered}$ |  | Room | -2 | - | 2 | nA |
|  |  |  |  | Full | -15 | - | 15 |  |
|  | $I_{\text {D(off) }}$ |  |  | Room | -2 | - | 2 |  |
|  |  |  |  | Full | -15 | - | 15 |  |
| Channel on leakage current ${ }^{\text {a }}$ | $\mathrm{I}_{\mathrm{D} \text { (on) }}$ | $\mathrm{V}+=5.5 \mathrm{~V}$ <br> $\mathrm{V}_{\mathrm{D}}=\mathrm{V}_{\mathrm{S}}=1 \mathrm{~V}$ or 4 V , sequence each switch on |  | Room | -2 | - | 2 |  |
|  |  |  |  | Full | -15 | - | 15 |  |
| Digital Control |  |  |  |  |  |  |  |  |
| Logic high input voltage | $\mathrm{V}_{\text {INH }}$ | $\mathrm{V}+=5 \mathrm{~V}$ |  | Full | 2 | - | - | V |
| Logic low input voltage | $\mathrm{V}_{\text {INL }}$ |  |  | Full | - | - | 0.8 |  |
| Input current ${ }^{\text {a }}$ | $\mathrm{I}_{\mathrm{N}}$ | $\mathrm{V}_{\mathrm{AX}}=\mathrm{V}_{\mathrm{EN}}=2 \mathrm{~V}$ or 0.8 |  | Full | -1 | - | 1 | $\mu \mathrm{A}$ |
| Dynamic Characteristics |  |  |  |  |  |  |  |  |
| Transition time ${ }^{\text {e }}$ | $t_{\text {trans }}$ | $\begin{gathered} \mathrm{V}_{\mathrm{S} 1}=3.5 \mathrm{~V}, \mathrm{~V}_{\mathrm{S} 8}=0 \mathrm{~V},(\mathrm{DG9408E}) \\ \left.\mathrm{V}_{\mathrm{S} 1 \mathrm{~b}}=3.5 \mathrm{~V}, \mathrm{~V}_{\mathrm{S} 4 \mathrm{~b}}=0 \mathrm{~V}, \text { (DG94090 }\right) \\ \text { see fig. } 2 \end{gathered}$ |  | Room | - | 79 | 97 | ns |
|  |  |  |  | Full | - | - | 112 |  |
| Break-before-make time ${ }^{\text {e }}$ | topen | $\begin{aligned} & \mathrm{V}_{\mathrm{S}(\text { all })}=\mathrm{V}_{\mathrm{DA}}=3.5 \mathrm{~V} \\ & \text { see fig. } 4 \end{aligned}$ |  | Room | 2 | 35 | - |  |
|  |  |  |  | Full | - | - | - |  |
| Enable turn-on time ${ }^{\text {e }}$ | $\mathrm{t}_{\text {ON(EN) }}$ | $\begin{gathered} \mathrm{V}_{\mathrm{AX}}=0 \mathrm{~V}, \mathrm{~V}_{\mathrm{S} 1}=3.5 \mathrm{~V}(\mathrm{DG9408E}) \\ \mathrm{V}_{\mathrm{AX}}=0 \mathrm{~V}, \mathrm{~V}_{\mathrm{S} 1 \mathrm{~b}}=3.5 \mathrm{~V}(\mathrm{DG9409E}) \\ \text { see fig. } 3 \end{gathered}$ |  | Room | - | 83 | 95 |  |
|  |  |  |  | Full | - | - | 116 |  |
| Enable turn-off time ${ }^{\text {e }}$ | $\mathrm{t}_{\text {OFF (EN) }}$ |  |  | Room | - | 36 | 57 |  |
|  |  |  |  | Full | - | - | 61 |  |
| Charge injection ${ }^{\text {e }}$ | Q | $\mathrm{C}_{\mathrm{L}}=1 \mathrm{nF}, \mathrm{R}_{\mathrm{GEN}}=0, \mathrm{~V}_{\mathrm{GEN}}=0 \mathrm{~V}$ |  | Room | - | 3.7 | - | pC |
| Off isolation ${ }^{\text {e, h }}$ | OIRR | $R_{L}=1 \mathrm{k} \Omega, \mathrm{f}=100 \mathrm{kHz}$ |  | Room | - | -83 | - | dB |
| Crosstalk ${ }^{\text {e }}$ | $\mathrm{X}_{\text {TALK }}$ |  |  | Room | - | -90 | - |  |
| Source off capacitance ${ }^{e}$ | $\mathrm{C}_{\text {(off) }}$ | $\mathrm{f}=1 \mathrm{MHz}, \mathrm{V}_{\mathrm{S}}=0 \mathrm{~V}, \mathrm{~V}_{\mathrm{EN}}=0 \mathrm{~V}$ | DG9408E | Room | - | 19 | - | pF |
|  |  |  | DG9409E | Room | - | 18 | - |  |
| Drain off capacitance ${ }^{\text {e }}$ | $C_{\text {D(fff) }}$ | $\mathrm{f}=1 \mathrm{MHz}, \mathrm{V}_{\mathrm{D}}=0 \mathrm{~V}, \mathrm{~V}_{\mathrm{EN}}=2 \mathrm{~V}$ | DG9408E | Room | - | 149 | - |  |
|  |  |  | DG9409E | Room | - | 74 | - |  |
| Drain on capacitance ${ }^{\text {e }}$ | $C_{\text {(on) }}$ | $f=1 \mathrm{MHz}, \mathrm{V}_{\mathrm{D}}=0 \mathrm{~V}, \mathrm{~V}_{\mathrm{EN}}=0 \mathrm{~V}$ | DG9408E | Room | - | 170 | - |  |
|  |  |  | DG9409E | Room | - | 94 | - |  |
| Power Supplies |  |  |  |  |  |  |  |  |
| Power supply current | I+ | $\mathrm{V}_{\text {EN }}=\mathrm{V}_{\mathrm{A}}=0 \mathrm{~V}$ or $\mathrm{V}_{+}$ |  | Room | - | - | 1 | $\mu \mathrm{A}$ |

DG9408E, DG9409E

| SPECIFICATIONS (Single Supply 3 V ) |  |  |  |  |  |  |  |  |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| PARAMETER | SYMBOL | TEST CONDITIONS UNLESS OTHERWISE SPECIFIED$\begin{gathered} \mathrm{V}+=3 \mathrm{~V}, \pm 10 \%, \mathrm{~V}-=0 \mathrm{~V} \\ \mathrm{~V}_{\mathrm{EN}}=0.4 \mathrm{~V} \text { or } 1.8 \mathrm{~V}^{\mathrm{f}} \end{gathered}$ |  | TEMP. ${ }^{\text {b }}$ | $\begin{gathered} \text { LIMITS } \\ -40^{\circ} \mathrm{C} \text { to }+85^{\circ} \mathrm{C} \end{gathered}$ |  |  | UNIT |
|  |  |  |  | MIN. ${ }^{\text {c }}$ | TYP. ${ }^{\text {d }}$ | MAX. ${ }^{\text {c }}$ |  |
| Analog Switch |  |  |  |  |  |  |  |  |
| Analog signal range ${ }^{\text {e }}$ | $\mathrm{V}_{\text {ANALOG }}$ |  |  |  | Full | 0 | - | 3 | V |
| On-resistance | $\mathrm{R}_{\mathrm{ON}}$ | $\mathrm{V}+=2.7 \mathrm{~V}, \mathrm{~V}_{\mathrm{D}}=0.5 \mathrm{~V}$ or $2.2 \mathrm{~V}, \mathrm{I}_{\mathrm{S}}=5 \mathrm{~mA}$ |  | Room | - | 13 | 25.5 | $\Omega$ |
|  |  |  |  | Full | - | - | 26.5 |  |
| RoN match between channels 9 | $\Delta \mathrm{R}_{\text {ON }}$ | $\mathrm{V}+=2.7 \mathrm{~V}, \mathrm{~V}_{\mathrm{D}}=0.5 \mathrm{~V}$ or $2.2 \mathrm{~V}, \mathrm{I}_{\mathrm{S}}=5 \mathrm{~mA}$ |  | Room | - | - | 3.6 |  |
| On-resistance flatness ${ }^{\text {i }}$ | $\mathrm{R}_{\mathrm{ON}}$ Flatness |  |  | Room | - | - | 13 |  |
| Switch off leakage current a | $\mathrm{I}_{\text {S(off) }}$ | $\begin{gathered} V_{+}=3.3 \mathrm{~V} \\ \mathrm{~V}_{\mathrm{S}}=2 \mathrm{~V} \text { or } 1 \mathrm{~V}, \mathrm{~V}_{\mathrm{D}}=1 \text { or } 2 \mathrm{~V} \end{gathered}$ |  | Room | -2 | - | 2 | nA |
|  |  |  |  | Full | -15 | - | 15 |  |
|  | $\mathrm{I}_{\mathrm{D} \text { (off) }}$ |  |  | Room | -2 | - | 2 |  |
|  |  |  |  | Full | -15 | - | 15 |  |
| Channel on leakage current a | $I_{\text {d(on) }}$ | $V_{+}=3.3 \mathrm{~V}$ <br> $\mathrm{V}_{\mathrm{D}}=\mathrm{V}_{\mathrm{S}}=1 \mathrm{~V}$ or 2 V , sequence each switch on |  | Room | -2 | - | 2 |  |
|  |  |  |  | Full | -15 | - | 15 |  |
| Digital Control |  |  |  |  |  |  |  |  |
| Logic high input voltage | $\mathrm{V}_{\text {INH }}$ |  |  | Full | 1.8 | - | - |  |
| Logic low input voltage | $\mathrm{V}_{\text {INL }}$ |  |  | Full | - | - | 0.4 |  |
| Input current ${ }^{\text {a }}$ | IN | $\mathrm{V}_{\mathrm{AX}}=\mathrm{V}_{\mathrm{EN}}=1.8 \mathrm{~V}$ or 0.4 |  | Full | -1 | - | 1 | $\mu \mathrm{A}$ |
| Dynamic Characteristics |  |  |  |  |  |  |  |  |
| Transition time | ${ }^{\text {trRans }}$ | $\begin{gathered} \mathrm{V}_{\mathrm{S} 1}=1.5 \mathrm{~V}, \mathrm{~V}_{\mathrm{S} 8}=0 \mathrm{~V},(\mathrm{DG9408E}) \\ \mathrm{V}_{\mathrm{S} 1 \mathrm{~b}}=1.5 \mathrm{~V}, \mathrm{~V}_{\text {S4b }}=0 \mathrm{~V},(\mathrm{DG} 9409 \mathrm{E}) \\ \text { see fig. } 2 \end{gathered}$ |  | Room | - | 169 | 245 | ns |
|  |  |  |  | Full | - | - | 278 |  |
| Break-before-make time | $t_{\text {BBM }}$ | $\begin{gathered} \mathrm{V}_{\mathrm{S}(\mathrm{all})}=\mathrm{V}_{\mathrm{DA}}=1.5 \mathrm{~V} \\ \text { see fig. } 4 \end{gathered}$ |  | Room | 2 | 96 | - |  |
|  |  |  |  | Full | - | - | - |  |
| Enable turn-on time | $\mathrm{t}_{\text {On(EN }}$ | $\begin{gathered} \mathrm{V}_{\mathrm{AX}}=0 \mathrm{~V}, \mathrm{~V}_{\mathrm{S} 1}=1.5 \mathrm{~V}(\mathrm{DG9408E}) \\ \mathrm{V}_{\mathrm{AX}}=0 \mathrm{~V}, \mathrm{~V}_{\mathrm{S} 1 \mathrm{~b}}=1.5 \mathrm{~V}(\mathrm{DG9409E}) \\ \text { see fig. } 3 \end{gathered}$ |  | Room | - | 202 | 255 |  |
|  |  |  |  | Full | - | - | 272 |  |
| Enable turn-off time | $\mathrm{t}_{\text {OFF (EN) }}$ |  |  | Room | - | 72 | 97 |  |
|  |  |  |  | Full | - | - | 104 |  |
| Charge injection ${ }^{\text {e }}$ | Q | $\mathrm{C}_{\mathrm{L}}=1 \mathrm{nF}, \mathrm{R}_{\mathrm{GEN}}=0, \mathrm{~V}_{\mathrm{GEN}}=0 \mathrm{~V}$ |  | Room | - | 2.1 | - | pC |
| Off isolation e, h | OIRR | $\mathrm{f}=100 \mathrm{kHz}, \mathrm{R}_{\mathrm{L}}=1 \mathrm{k} \Omega$ |  | Room | - | -83 | - |  |
| Crosstalk ${ }^{\text {e }}$ | $\mathrm{X}_{\text {TALK }}$ |  |  | Room | - | -90 | - | dB |
| Source off capacitance ${ }^{e}$ | $\mathrm{C}_{\text {S(off) }}$ | $\mathrm{f}=1 \mathrm{MHz}, \mathrm{V}_{\mathrm{S}}=0 \mathrm{~V}, \mathrm{~V}_{\mathrm{EN}}=1.8 \mathrm{~V}$ | DG9408E | Room | - | 20 | - | pF |
|  |  |  | DG9409E | Room | - | 19 | - |  |
| Drain off capacitance ${ }^{\text {e }}$ | $C_{D(\text { (ff) }}$ | $\mathrm{f}=1 \mathrm{MHz}, \mathrm{V}_{\mathrm{D}}=0 \mathrm{~V}, \mathrm{~V}_{\mathrm{EN}}=1.8 \mathrm{~V}$ | DG9408E | Room | - | 159 | - |  |
|  |  |  | DG9409E | Room | - | 79 | - |  |
| Drain on capacitance ${ }^{\text {e }}$ | $\mathrm{C}_{\text {(on) }}$ | $\mathrm{f}=1 \mathrm{MHz}, \mathrm{V}_{\mathrm{D}}=0 \mathrm{~V}, \mathrm{~V}_{\text {EN }}=0 \mathrm{~V}$ | DG9408E | Room | - | 179 | - |  |
|  |  |  | DG9409E | Room | - | 98 | - |  |
| Power Supplies |  |  |  |  |  |  |  |  |
| Power supply current | I+ | $\mathrm{V}_{\mathrm{EN}}=\mathrm{V}_{\mathrm{A}}=0 \mathrm{~V}$ or $\mathrm{V}_{+}$ |  | Room | - | - | 1 | $\mu \mathrm{A}$ |

## Notes

a. Leakage parameters are guaranteed by worst case test condition and not subject to production test.
b. Room $=25^{\circ} \mathrm{C}$, full $=$ as determined by the operating temperature suffix.
c. The algebraic convention whereby the most negative value is a minimum and the most positive a maximum, is used in this data sheet.
d. Typical values are for DESIGN AID ONLY, not guaranteed nor subject to production testing.
e. Guaranteed by design, not subject to production test.
f. $\mathrm{V}_{\mathbb{I N}}=$ input voltage to perform proper function.
g. $\Delta R_{\text {DON }}=R_{\text {DON }}$ max. $-R_{\text {DON }} \min$.
h. Worst case isolation occurs on channel 4 due to proximity to the drain pin.
i. $R_{\text {DoN }}$ flatness is measured as the difference between the minimum and maximum measured values across a defined analog signal.

TYPICAL CHARACTERISTICS $\left(25^{\circ} \mathrm{C}\right.$, unless otherwise noted)


On-Resistance vs. Analog Voltage


On-Resistance vs. Analog Voltage


On-Resistance vs. Analog Voltage


On-Resistance vs. Analog Voltage


On-Resistance vs. Analog Voltage


On-Resistance vs. Analog Voltage

TYPICAL CHARACTERISTICS $\left(25^{\circ} \mathrm{C}\right.$, unless otherwise noted)


Leakage Current vs. Analog Voltage


Leakage Current vs. Analog Voltage


Leakage Current vs. Temperature


Supply Current vs. Temperature


Loss, OIRR, $X_{\text {TALK }}$ vs. Frequency


Loss, OIRR, $X_{\text {TALK }}$ vs. Frequency

TYPICAL CHARACTERISTICS $\left(25^{\circ} \mathrm{C}\right.$, unless otherwise noted)


Supply Current vs. Input Switching Frequency


Switching Time vs. Temperature


Transition Time vs. Temperature


Switching Threshold vs. Supply Voltage


Charge Injection vs. Analog Voltage


Capacitance vs. Analog Voltage

TYPICAL CHARACTERISTICS $\left(25^{\circ} \mathrm{C}\right.$, unless otherwise noted)


Capacitance vs. Analog Voltage

SCHEMATIC DIAGRAM (Typical Channel)


Fig. 1 -

## TEST CIRCUITS




Return to Specifications:
Single Supply 12 V
Dual Supply V+=5V, V- = -5 V
Single Supply 5 V
Single Supply 3 V

Fig. 2 - Transition Time


Fig. 3 - Enable Switching Time

Vishay Siliconix

## TEST CIRCUITS



Return to Specifications:
Single Supply 12 V
Dual Supply V+=5V, V- =-5 V
Single Supply 5 V
Single Supply 3 V
Fig. 4 - Break-Before-Make Interval


Fig. 5 - Charge Injection


Fig. 6 - Off Isolation

## TEST CIRCUITS



Fig. 7 - Crosstalk


Fig. 8 - Insertion Loss


Fig. 9 - Source Drain Capacitance

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## QFN 4x4-16L Case Outline



TIP VIEW


BOTTOM VIEW


SIDE VIEW

| DIM | VARIATION 1 |  |  |  |  |  | VARIATION 2 |  |  |  |  |  |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  | MILLIMETERS ${ }^{(1)}$ |  |  | INCHES |  |  | MILLIMETERS ${ }^{(1)}$ |  |  | INCHES |  |  |
|  | MIN. | NOM. | MAX. | MIN. | NOM. | MAX. | MIN. | NOM. | MAX. | MIN. | NOM. | MAX. |
| A | 0.75 | 0.85 | 0.95 | 0.029 | 0.033 | 0.037 | 0.75 | 0.85 | 0.95 | 0.029 | 0.033 | 0.037 |
| A1 | 0 | - | 0.05 | 0 | - | 0.002 | 0 | - | 0.05 | 0 | - | 0.002 |
| A3 | 0.20 ref. |  |  | 0.008 ref. |  |  | 0.20 ref. |  |  | 0.008 ref. |  |  |
| b | 0.25 | 0.30 | 0.35 | 0.010 | 0.012 | 0.014 | 0.25 | 0.30 | 0.35 | 0.010 | 0.012 | 0.014 |
| D | 4.00 BSC |  |  | 0.157 BSC |  |  | 4.00 BSC |  |  | 0.157 BSC |  |  |
| D2 | 2.0 | 2.1 | 2.2 | 0.079 | 0.083 | 0.087 | 2.5 | 2.6 | 2.7 | 0.098 | 0.102 | 0.106 |
| e | 0.65 BSC |  |  | 0.026 BSC |  |  | 0.65 BSC |  |  | 0.026 BSC |  |  |
| E | 4.00 BSC |  |  | 0.157 BSC |  |  | 4.00 BSC |  |  | 0.157 BSC |  |  |
| E2 | 2.0 | 2.1 | 2.2 | 0.079 | 0.083 | 0.087 | 2.5 | 2.6 | 2.7 | 0.098 | 0.102 | 0.106 |
| K | 0.20 min . |  |  | 0.008 min . |  |  | 0.20 min . |  |  | 0.008 min . |  |  |
| L | 0.5 | 0.6 | 0.7 | 0.020 | 0.024 | 0.028 | 0.3 | 0.4 | 0.5 | 0.012 | 0.016 | 0.020 |
| $N^{(3)}$ | 16 |  |  | 16 |  |  | 16 |  |  | 16 |  |  |
| Nd(3) | 4 |  |  | 4 |  |  | 4 |  |  | 4 |  |  |
| $\mathrm{Ne}^{(3)}$ | 4 |  |  | 4 |  |  | 4 |  |  | 4 |  |  |

## Notes

(1) Use millimeters as the primary measurement.
(2) Dimensioning and tolerances conform to ASME Y14.5M. - 1994.
(3) N is the number of terminals. Nd and Ne is the number of terminals in each D and E site respectively.
(4) Dimensions b applies to plated terminal and is measured between 0.15 mm and 0.30 mm from terminal tip.
(5) The pin 1 identifier must be existed on the top surface of the package by using identification mark or other feature of package body.
(6) Package warpage max. 0.05 mm .

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DWG: }589
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